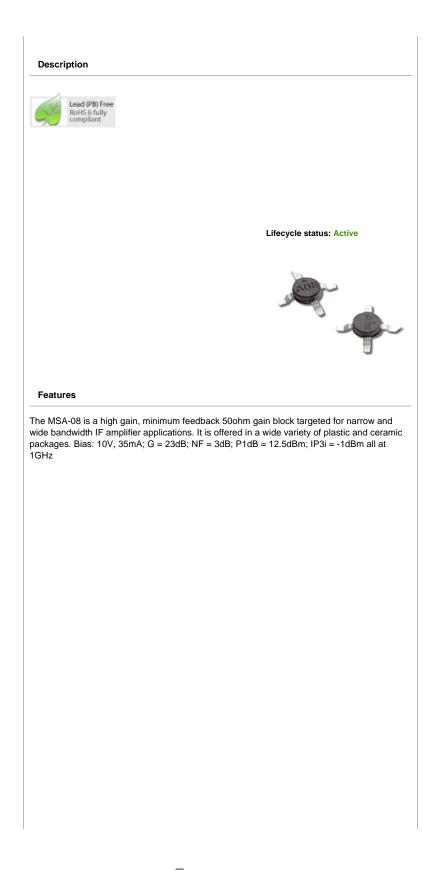
Products > RF ICs/Discretes > RF ICs > Silicon Amplifiers, Gain Blocks > MSA-0886

MSA-0886 >6V fixed gain amp



MSA-0886 Cascadable Silicon Bipolar MMIC Amplifier



Data Sheet

Description

The MSA-0886 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost, surface mount plastic package. This MMIC is designed for use as a general purpose 50Ω gain block above 0.5 GHz and can be used as a high gain transistor below this frequency. Typical applications include narrow and moderate band IF and RF amplifiers in commercial and industrial applications.

The MSA-series is fabricated using Avago's 10 GHz $f_{\rm T},$ 25 GHz $f_{\rm MAX},$ silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

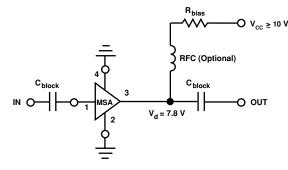
Features

- Lead-free Option Available
- Usable Gain to 5.5 GHz
- High Gain: 32.5 dB Typical at 0.1 GHz 22.5 dB Typical at 1.0 GHz
- Low Noise Figure: 3.3 dB Typical at 1.0 GHz
- Surface Mount Plastic Package
- Tape-and-Reel Packaging Option Available
- · Lead-free Option Available

86 Plastic Package



Typical Biasing Configuration



MSA-0886 Absolute Maximum Ratings

Parameter	Absolute Maximum ^[1]	
Device Current	65 mA	
Power Dissipation ^[2,3]	500 mW	
RF Input Power	+13 dBm	
Junction Temperature	150°C	
Storage Temperature	–65°C to 150°C	

Thermal Resistance^[2]:

 $\theta_{jc} = 140^{\circ}C/W$

Notes:

1. Permanent damage may occur if any of these limits are exceeded.

2. $T_{CASE} = 25^{\circ}C.$

3. Derate at 7.1 mW/°C for $T_C > 80^\circ C.$

Electrical Specifications^[1], $T_A = 25^{\circ}C$

Symbol	Parameters and Test Conditions: I_d = 36 mA, Z_0 = 50 Ω			Min.	Тур.	Max.
Gp	Power Gain (S ₂₁ ²)	f = 0.1 GHz f = 1.0 GHz	dB	20.5	32.5 22.5	
VSWR	Input VSWR	f = 0.1 to 3.0 GHz			2.1:1	
	Output VSWR	f = 0.1 to 3.0 GHz			1.9:1	
NF	50 Ω Noise Figure	f = 1.0 GHz	dB		3.3	
P1 dB	Output Power at 1 dB Gain Compression	f = 1.0 GHz	dBm		12.5	
IP ₃	Third Order Intercept Point	f = 1.0 GHz	dBm		27.0	
tD	Group Delay	f = 1.0 GHz	psec		140	
Vd	Device Voltage		V	6.2	7.8	9.4
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-17.0	

Note:

1. The recommended operating current range for this device is 20 to 40 mA. Typical performance as a function of current is on the following page.

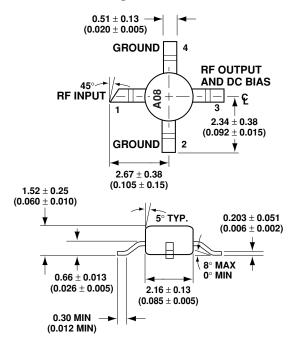
Ordering Information

Part Numbers	No. of Devices	Comments
MSA-0886-BLK	100	Bulk
MSA-0886-BLKG	100	Bulk
MSA-0886-TR1	1000	7" Reel
MSA-0886-TR1G	1000	7" Reel
MSA-0886-TR2	4000	13" Reel
MSA-0886-TR2G	4000	13" Reel

Note: Order part number with a "G" suffix if lead-free option is desired.

2

86 Plastic Package Dimensions



DIMENSIONS ARE IN MILLIMETERS (INCHES)

